Ordering & quality

Technical documentation

Design & development

Support & training

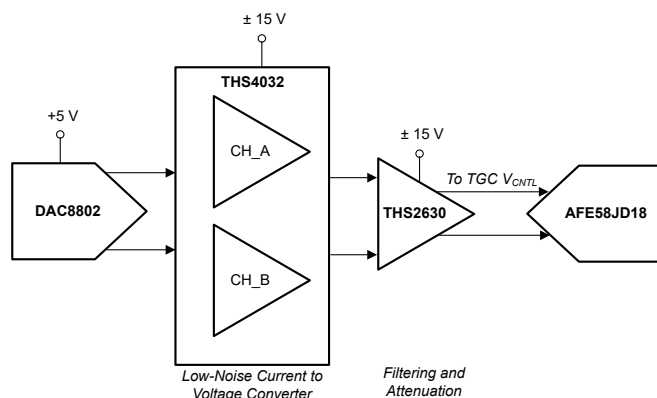TEXAS INSTRUMENTS

THS2630
ZHCSQB3A – JANUARY 2023 – REVISED JULY 2023

THS2630 高速、低噪声、全差分 I/O 放大器

1 特性

- 高性能
  - 带宽：187MHz（V_{CC} = ±15V，G = 1V/V）
  - 压摆率：75V/μs
  - 增益带宽积：245MHz
  - 失真：-108dBc THD（$2V_{PP}$、250kHz 时）
- 电压噪声
  - 1/f 电压噪声拐角频率：85Hz
  - 输入基准噪声 1.1nV/√Hz
- 单电源电压范围：5V 至 35V
- 静态电流（关断）：770μA (THS2630S)

2 应用

- 单端至差分转换
- 差分 ADC 驱动器
- 差分抗混叠
- 差分发送器和接收器
- 输出电平转换器
- 医疗超声波

3 说明

THS2630 属于全差分输入和差分输出器件系列，该系列器件使用德州仪器 (TI) 先进的高压互补双极工艺制造。

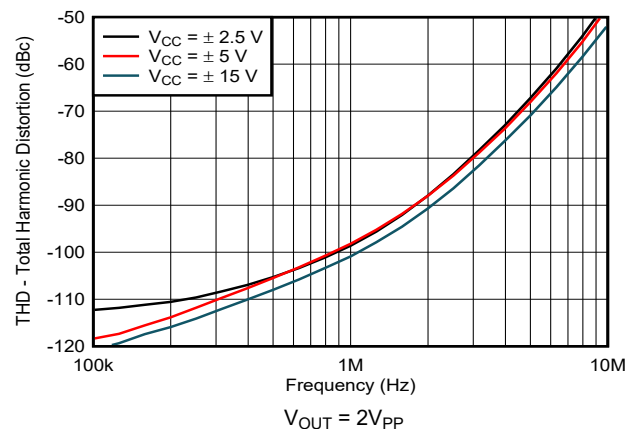THS2630 使用从输入到输出的真正全差分信号路径，具有高达 ±17.5V 的高电源电压。这种设计带来了出色的共模噪声抑制能力（800kHz 时为 95dB）和总谐波失真（$2V_{PP}$、250kHz 时为 −108dBc）。高电压差分信号链可通过宽电源电压范围提高裕量和动态范围，而无需为差分信号的每个极性添加单独的放大器。

THS2630 在 −40°C 至 +85°C 的宽温度范围内运行。

封装信息

器件型号	封装[1]		封装尺寸[2]
THS2630	D（SOIC，8）		4.9 mm × 6 mm
	DGK（VSSOP，8）		3 mm × 4.9 mm
	DGN（HVSSOP，8）		3 mm × 4.9 mm

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。

(2) 封装尺寸（长 x 宽）为标称值，并包括引脚（如适用）。

适用于超声波的
时间增益控制 **DAC** 参考设计

V_{OUT} = $2V_{PP}$

总谐波失真与频率间的关系

English Data Sheet: SLOSE96

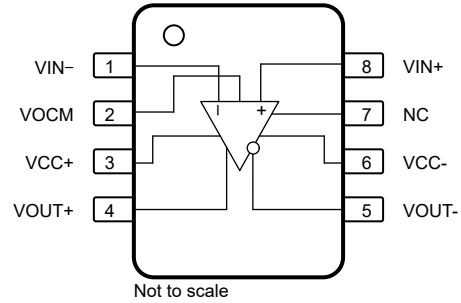# Table of Contents

4 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision * (January 2023) to Revision A (July 2023)	Page
• 将数据表状态从"预告信息（预发布）"更改为"量产数据（正在供货）"..1	

5 Pin Configuration and Functions
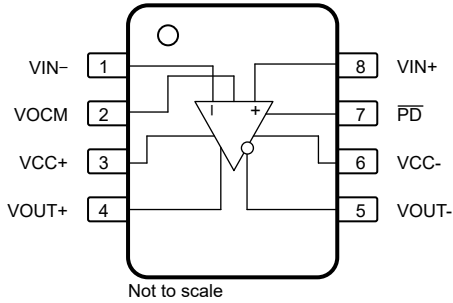
图 **5-1. D Package, 8-Pin SOIC**
DGK Package, 8-Pin VSSOP
or DGN Package, 8-Pin HVSSOP
THS2630S (Top View)

图 **5-2. D Package, 8-Pin SOIC**
DGK Package, 8-Pin VSSOP
or DGN Package, 8-Pin HVSSOP
THS2630 (Top View)

表 **5-1. Pin Functions**

PIN			TYPE[(1)]	DESCRIPTION
NAME	NO.			
	THS2630S	THS2630		
IN –	1	1	I	Negative input pin
IN+	8	8	I	Positive input pin
NC	—	7	—	This pin is not internally connected; leave floating or connect to any other pin on the device.
OUT –	5	5	O	Negative output pin
OUT+	4	4	O	Positive output pin
$\overline{PD}$	7	—	I	Active low power-down pin
VCC+	3	3	I/O	Positive supply voltage pin
VCC –	6	6	I/O	Negative supply voltage pin
VOCM	2	2	I	Common mode input pin
Thermal Pad	Thermal Pad	Thermal Pad	—	Thermal pad. DGN (HVSSOP) package only. For the best thermal performance, connect this pad to a large copper plane. The thermal pad can be connected to any pin on the device, or any other potential on the board, as long as the voltage on the thermal pad remains between VCC+ and VCC – .

(1)   I = input, O = output

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)[1]

		MIN	MAX	UNIT
V_I	Input voltage	$-V_{CC}$	$+V_{CC}$	V
V_{CC-} to V_{CC+}	Supply voltage		37	V
	Supply turn on and turn off dV/dT[2]		1.7	V/µs
I_O	Output current[3]		150	mA
V_{ID}	Differential input voltage	−1.5	1.5	V
I_{IN}	Continuous input current		10	mA
T_J	Junction temperature		150	°C
	Junction temperature, continuous operation, long-term reliability		125	°C
T_A	Ambient temperature	0	85	°C
T_{stg}	Storage temperature	−65	150	°C

(1)   Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute maximum ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If briefly operating outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not sustain damage, but it may not be fully functional. Operating the device in this manner may affect device reliability, functionality, performance, and shorten the device lifetime.

(2)   Stay below this specification to make sure that the edge-triggered ESD absorption devices across the supply pins remain off.

(3)   The THS2630 HVSSOP PowerPAD integrated circuit package incorporates a thermal pad on the underside of the chip. This thermal pad acts as a heat sink and must be connected to a thermally dissipative plane for proper power dissipation. Failure to do so can result in exceeding the maximum junction temperature which can permanently damage the device. See TI technical briefs SLMA002 and SLMA004 for more information about using the PowerPAD integrated circuit package.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001[1]	±3500	V
		Charged-device model (CDM), per ANSI/ESDA/JEDEC JS-002[2]	±1500	

(1)   JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2)   JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage	Dual supply	±2.5		±17.5	V
		Single supply	5		35	
T_A	Operating free-air temperature		−40		85	°C

6.4 Thermal Information

		THS2630			
THERMAL METRIC[1]		D (SOIC)	DGK (VSSOP)	DGN (HVSSOP)	UNIT
		8 PINS	8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	126.3	147.3	57.6	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	67.3	37.9	76.3	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	69.8	83.2	30.0	°C/W
ψ_{JT}	Junction-to-top characterization parameter	19.5	0.9	4.0	°C/W
ψ_{JB}	Junction-to-board characterization parameter	69.0	81.6	29.9	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	14.3	°C/W

(1)   For information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.5 Electrical Characteristics

at V_{CC} = ±5 V, gain = 1 V/V, R_F = 390 Ω, R_L = 800 Ω, and T_A = +25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
DYNAMIC PERFORMANCE							
SSBW	Small-signal bandwidth (–3 dB)	Gain = 1, R_F = 390 Ω, V_I = 63 mV_{PP}, single-ended input, differential output	V_{CC} = 5 V		181		MHz
			V_{CC} = ±5 V		183		
			V_{CC} = ±15 V		187		
		Gain = 2, R_F = 750 Ω, V_I = 63 mV_{PP}, single-ended input, differential output	V_{CC} = 5 V		108		
			V_{CC} = ±5 V		108		
			V_{CC} = ±15 V		111		
	VOCM small-signal bandwidth	V_I = 63 mV_{PP}			100		MHz
GBW	Gain-bandwidth product	V_O = 200 mV_{PP}, gain = 20, R_F = 750 Ω			245		MHz
SR	Slew rate[2]				75		V/µs
t_s	Settling time	To 0.1%	Step voltage = 2 V, gain = 1		31		ns
		To 0.01%	Step voltage = 2 V, gain = 1		52		
DISTORTION PERFORMANCE							
THD	Total harmonic distortion	V_{CC} = 5 V, V_O = 2 V_{PP}, differential input/output	f = 250 kHz		–106		dBc
			f = 1 MHz		–93		
		V_{CC} = ±5 V, V_O = 2 V_{PP}, differential input/output	f = 250 kHz		–106		
			f = 1 MHz		–93		
		V_{CC} = ±15 V, V_O = 2 V_{PP}, differential input/output	f = 250 kHz		–108		
			f = 1 MHz		–94		
		V_{CC} = ±5 V, V_O = 4 V_{PP}, differential input/output	f = 250 kHz		–99		
			f = 1 MHz		–84		
		V_{CC} = ±15 V, V_O = 4 V_{PP}, differential input/output	f = 250 kHz		–100		
			f = 1 MHz		–86		
HD2	Second harmonic distortion	V_{CC} = 5 V, V_O = 2 V_{PP}, R_f = 390 Ω, R_L = 800 Ω, gain = 1, differential input/output	f = 250 kHz		–116		dBc
			f = 1 MHz		–106		
		V_{CC} = ±5 V, V_O = 2 V_{PP}, R_f = 390 Ω, R_L = 800 Ω, gain = 1, differential input/output	f = 250 kHz		–116		
			f = 1 MHz		–106		
		V_{CC} = ±15 V, V_O = 2 V_{PP}, R_f = 390 Ω, R_L = 800 Ω, gain = 1, differential input/output	f = 250 kHz		–117		
			f = 1 MHz		–107		
		V_{CC} = ±5 V, V_O = 4 V_{PP}, R_f = 390 Ω, R_L = 800 Ω, gain = 1, differential input/output	f = 250 kHz		–115		
			f = 1 MHz		–101		
		V_{CC} = ±15 V, V_O = 4 V_{PP}, R_f = 390 Ω, R_L = 800 Ω, gain = 1, differential input/output	f = 250 kHz		–116		
			f = 1 MHz		–102		

Product Folder Links: THS2630

English Data Sheet: SLOSE96

6.5 Electrical Characteristics (continued)

at V_{CC} = ±5 V, gain = 1 V/V, R_F = 390 Ω, R_L = 800 Ω, and T_A = +25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
HD3	Third harmonic distortion	V_{CC} = 5 V, V_O = 2 V_{PP}, R_f = 390 Ω, R_L = 800 Ω, gain = 1, differential input/output	f = 250 kHz		−111		dBc
			f = 1 MHz		−100		
		V_{CC} = ±5 V, V_O = 2 V_{PP}, R_f = 390 Ω, R_L = 800 Ω, gain = 1, differential input/output	f = 250 kHz		−114		
			f = 1 MHz		−99		
		V_{CC} = ±15 V, V_O = 2 V_{PP}, R_f = 390 Ω, R_L = 800 Ω, gain = 1, differential input/output	f = 250 kHz		−117		
			f = 1 MHz		−102		
		V_{CC} = ±5 V, V_O = 4 V_{PP}, R_f = 390 Ω, R_L = 800 Ω, gain = 1, differential input/output	f = 250 kHz		−107		
			f = 1 MHz		−91		
		V_{CC} = ±15 V, V_O = 4 V_{PP}, R_f = 390 Ω, R_L = 800 Ω, gain = 1, differential input/output	f = 250 kHz		−110		
			f = 1 MHz		−93		
SFDR	Spurious-free dynamic range	V_O = 2 V_{PP}, f = 250 kHz, differential input/output	V_{CC} = ±2.5		109		dBc
			V_{CC} = ±5		112		
			V_{CC} = ±15		116		
		V_O = 4 V_{PP}, f = 250 kHz, differential input/output	V_{CC} = ±5		104		
			V_{CC} = ±15		106		
IMD3	Third intermodulation distortion	$V_{I(PP)}$ = 4 V, F_1 = 3 MHz, F_2 = 3.5 MHz			−53		dBc
OIP3	Third-order intercept	$V_{I(PP)}$ = 4 V, F_1 = 3 MHz, F_2 = 3.5 MHz			41.5		dB
NOISE PERFORMANCE							
V_n	Input voltage noise	f = 10 kHz			1.1		nV/√Hz
I_n	Input current noise	f = 10 kHz			1.3		pA/√Hz
DC PERFORMANCE							
A_{OL}	Open-loop gain	T_A = 25°C		91	95		dB
		T_A = full range		85			
V_{OS}	Input offset voltage	T_A = 25°C		−1.3	±0.1	1.3	mV
		T_A = full range				1.5	
	Input offset voltage drift	T_A = full range			0.8	3.2	µV/°C
I_{IB}	Input bias current	T_A = 25℃			4.8	9.8	µA
		T_A = full range			4.8	15.1	
I_{OS}	Input offset current	T_A = 25℃		−250	22	350	nA
		T_A = full range				400	
	Input offset current drift				0.13		nA/°C
INPUT CHARACTERISTICS							
CMRR	Common-mode rejection ratio	T_A = 25℃		81	95		dB
V_{ICM}	Common-mode input voltage			−3.77 to 4.3	−4 to 4.5		V
R_I	Input resistance	Common-mode, measured into each input pin			320		MΩ
		Differential, measured into each input pin			12		kΩ

Product Folder Links: THS2630

6.5 Electrical Characteristics (continued)

at V_{CC} = ±5 V, gain = 1 V/V, R_F = 390 Ω, R_L = 800 Ω, and T_A = +25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
C_{I_CM}	Common-mode input capacitance	Measured into each input pin, closed loop			1.3		pF
C_{I_DIFF}	Differential input capacitance	Measured into each input pin, closed loop			2.3		pF
OUTPUT CHARACTERISTICS							
R_O	Output resistance	Open loop			26		Ω
	Output voltage swing	V_{CC} = ±15 V, R_L = 1 kΩ	T_A = 25°C	±13.1	±13.4		V
			T_A = full range	±12.9			V
I_O	Output current	V_{CC} = 5 V, R_L = 7 Ω	T_A = 25°C	25	45		mA
			T_A = full range	20			
		V_{CC} = ±5 V, R_L = 7 Ω	T_A = 25°C	30	55		
			T_A = full range	28			
		V_{CC} = ±15 V, R_L = 7 Ω	T_A = 25°C	65	85		
			T_A = full range	60			
POWER SUPPLY							
I_Q	Quiescent current	V_{CC} = ±5 V	T_A = 25°C		8.9	10.5	mA
			T_A = full range			12.4	
		V_{CC} = ±15 V			11	13.2	
		V_{CC} = ±17.5 V			11	13.2	
I_{SD}	Shutdown current (THS2630S only)	$\overline{PD}$ = –5 V			0.77	0.92	mA
PSRR	Power-supply rejection ratio			76	98		dB
OUTPUT COMMON-MODE (VOCM) CONTROL							
	V_{OCM} offset voltage	V_{OCM} driven to midsupply		−2.7	0.2	2.7	mV
	Default V_{OCM} offset	Relative to midsupply, VOCM pin floating		−10	0.65	10	mV
	V_{OCM} input range low	V_{CC} = ±15 V			–14		V
		V_{CC} = ±5 V			–4.1	–4	
	V_{OCM} input range high	V_{CC} = ±15 V			13.7		V
		V_{CC} = ±5 V		3.5	3.8		
	V_{OCM} input noise	Flat-band noise, VOCM driven			13		nV/$\sqrt{Hz}$
	V_{OCM} input resistance				15		kΩ

(1) Slew rate is measured from an output level range of 25% to 75%.

Product Folder Links: *THS2630*

English Data Sheet: *SLOSE96*

6.6 Typical Characteristics

at T_A = 25°C, V_{CC} = ±5 V, R_F = 390 Ω, G = +1 V/V, differential input/output, and R_L = 800 Ω (unless otherwise noted)
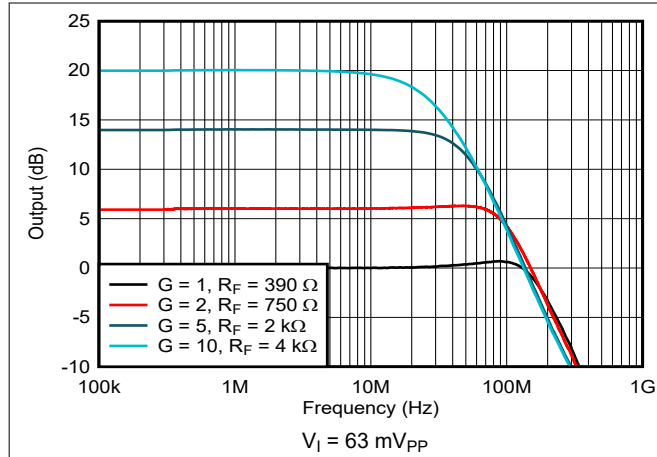

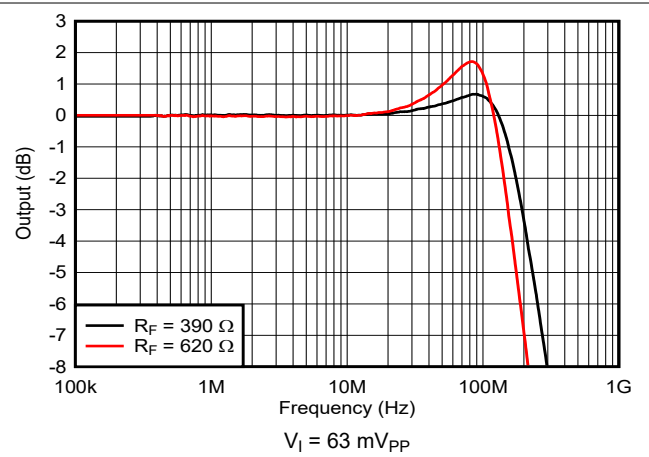图 6-1. Small-Signal Frequency Response
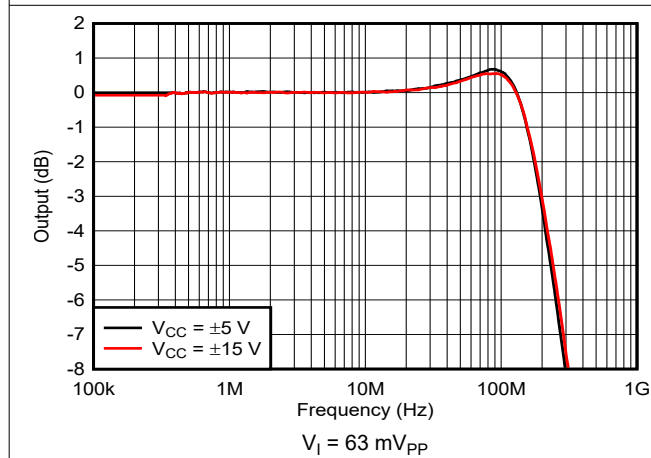

图 6-2. Small-Signal Frequency Response

图 6-3. Small-Signal Frequency Response

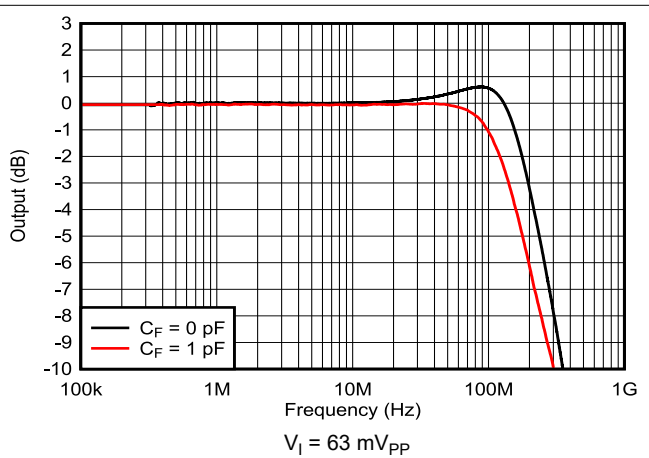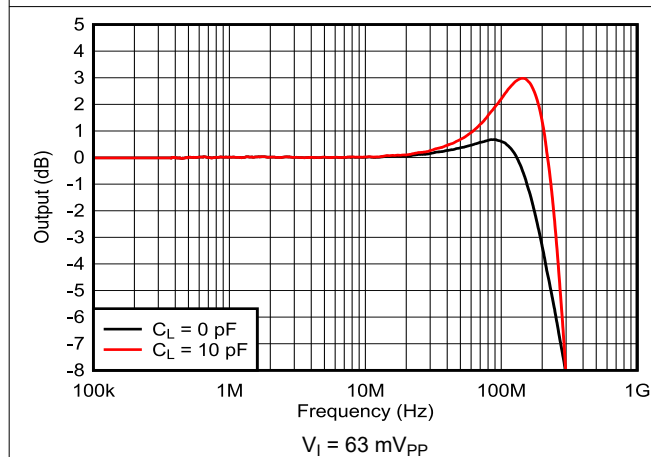
图 6-4. Small-Signal Frequency Response
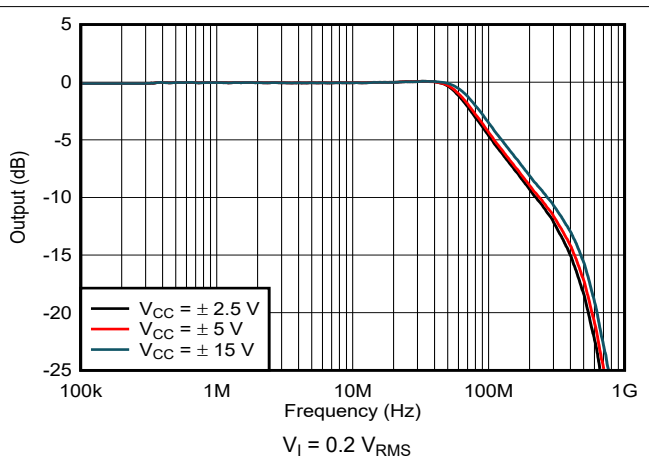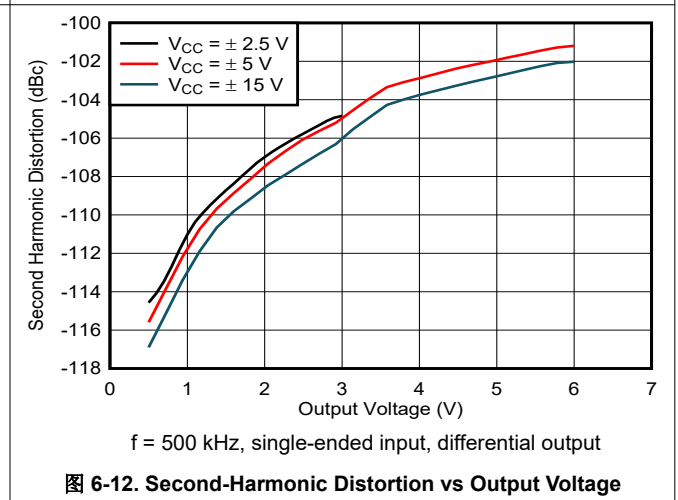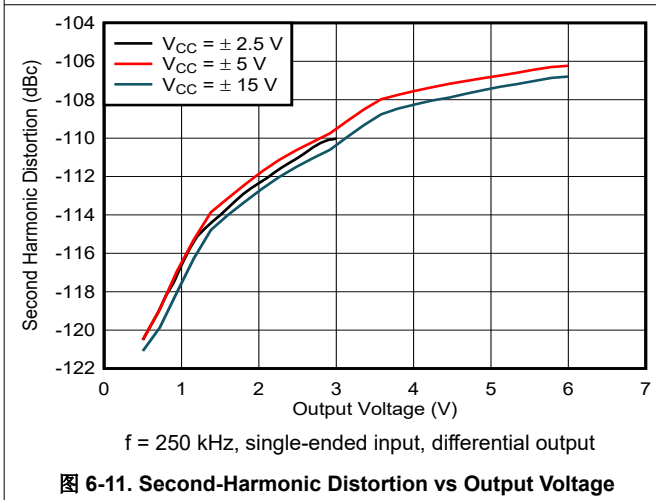

图 6-5. Small-Signal Frequency Response

图 6-6. Large-Signal Frequency Response

Product Folder Links: THS2630

6.6 Typical Characteristics (continued)

at T_A = 25°C, V_{CC} = ±5 V, R_F = 390 Ω, G = +1 V/V, differential input/output, and R_L = 800 Ω (unless otherwise noted)

R_F = 510 Ω, C_F= 1 pF, V_{CC}= 5 V, V_O = 4 V_{PP}

图 6-7. Settling Time

V_{OUT} = 2 V_{PP}

图 6-8. Total Harmonic Distortion vs Frequency

V_{OUT} = 2 V_{PP}, single-ended input, differential output

图 6-9. Second-Harmonic Distortion vs Frequency

V_{OUT} = 4 V_{PP}, single-ended input, differential output

图 6-10. Second-Harmonic Distortion vs Frequency

f = 250 kHz, single-ended input, differential output

图 6-11. Second-Harmonic Distortion vs Output Voltage

f = 500 kHz, single-ended input, differential output

图 6-12. Second-Harmonic Distortion vs Output Voltage

Product Folder Links: THS2630

English Data Sheet: SLOSE96

6.6 Typical Characteristics (continued)

at T_A = 25°C, V_{CC} = ±5 V, R_F = 390 Ω, G = +1 V/V, differential input/output, and R_L = 800 Ω (unless otherwise noted)

V_{OUT} = 4 V_{PP}, single-ended input, differential output

图 6-13. Third-Harmonic Distortion vs Frequency

v_{out} = 2 v_{pp}, single-ended input, differential output

图 6-14. Third-Harmonic Distortion vs Frequency

f = 500 kHz, single-ended input, differential output

图 6-15. Third-Harmonic Distortion vs Output Voltage

f = 250 kHz, single-ended input, differential output

图 6-16. Third-Harmonic Distortion vs Output Voltage

R_F = 1 kΩ

图 6-17. Common-Mode Rejection Ratio vs Frequency
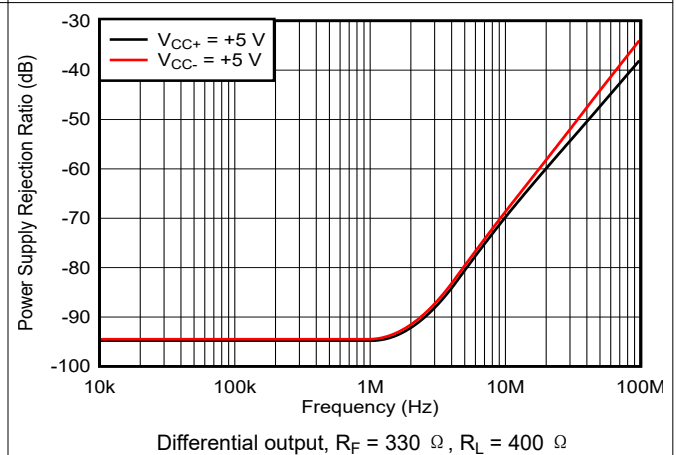
Differential output, R_F = 330 Ω, R_L = 400 Ω

图 6-18. Power-Supply Rejection Ratio vs Frequency

Product Folder Links: *THS2630*

English Data Sheet: *SLOSE96*

6.6 Typical Characteristics (continued)

at T_A = 25°C, V_{CC} = ±5 V, R_F = 390 Ω, G = +1 V/V, differential input/output, and R_L = 800 Ω (unless otherwise noted)
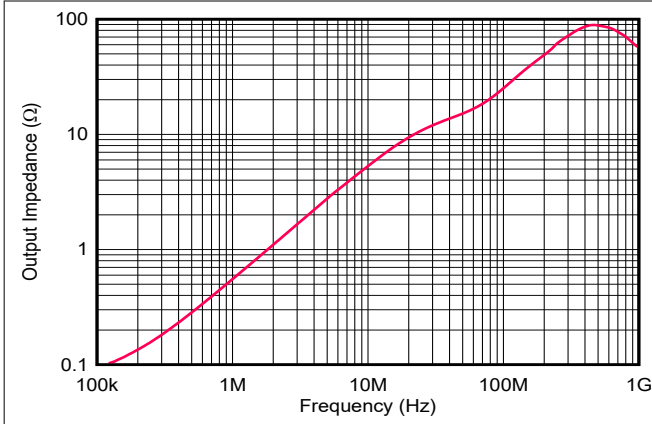
图 6-19. Output Impedance vs Frequency
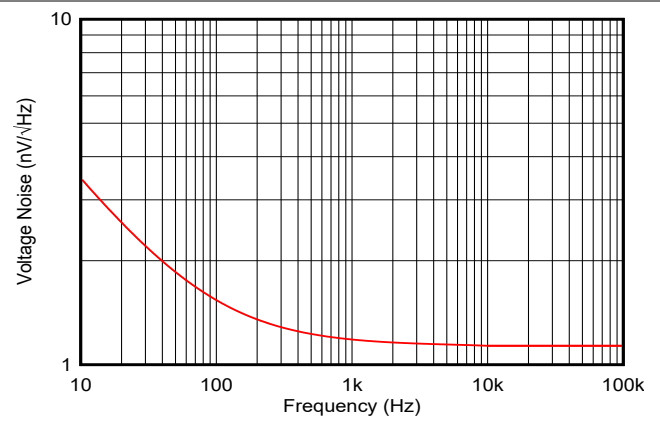
图 6-20. Voltage Noise vs Frequency
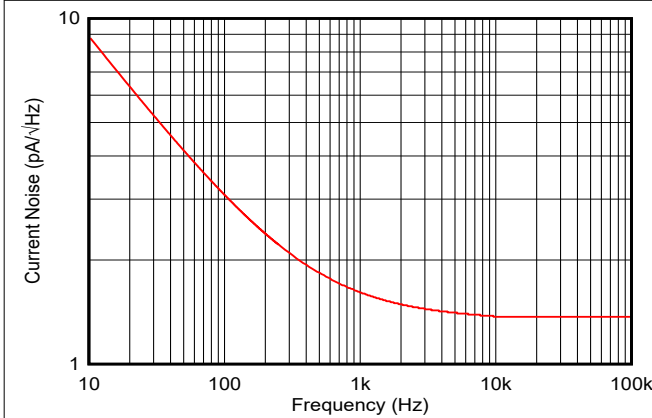
图 6-21. Current Noise vs Frequency

Differential input, single-ended output
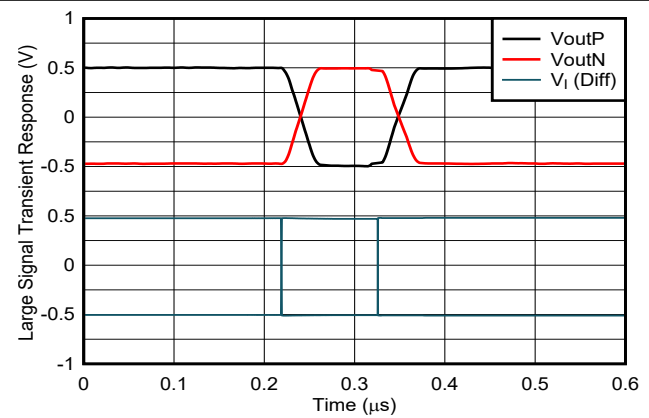
图 6-22. Large-Signal Transient Response
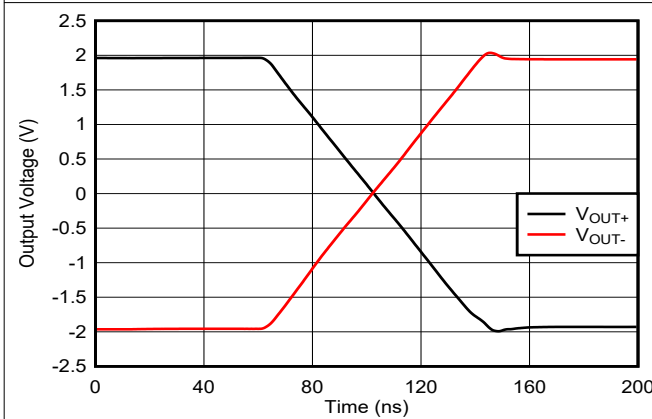
V_{I_Peak} = 2 V, C_L = 10 pF, V_{CC} = ±15 V

图 6-23. Large-Signal Transient Response
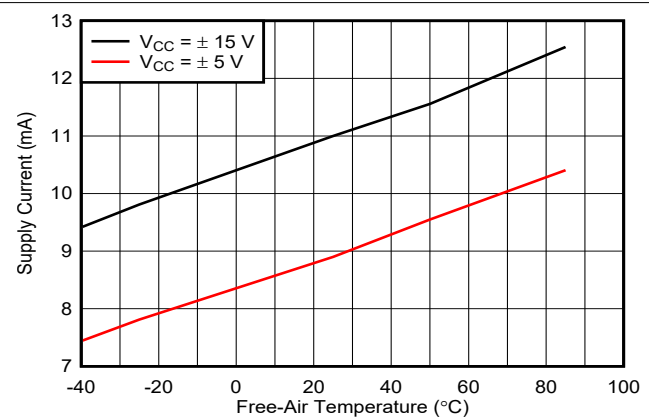
图 6-24. Supply Current vs Free-Air Temperature

Product Folder Links: THS2630

English Data Sheet: SLOSE96

6.6 Typical Characteristics (continued)

at T_A = 25°C, V_{CC} = ±5 V, R_F = 390 Ω, G = +1 V/V, differential input/output, and R_L = 800 Ω (unless otherwise noted)
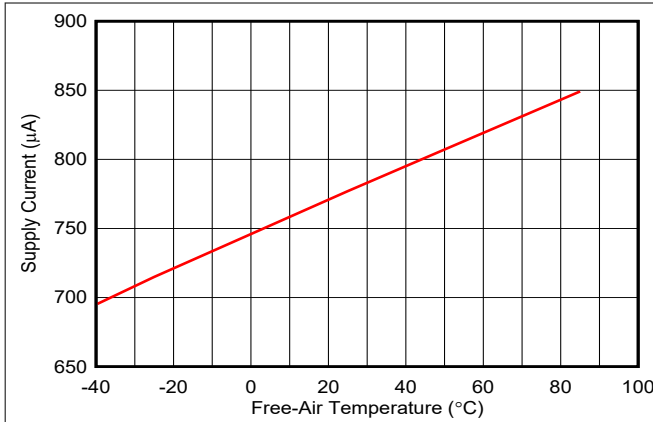
图 **6-25. Supply Current vs Free-Air Temperature (Shutdown State)**
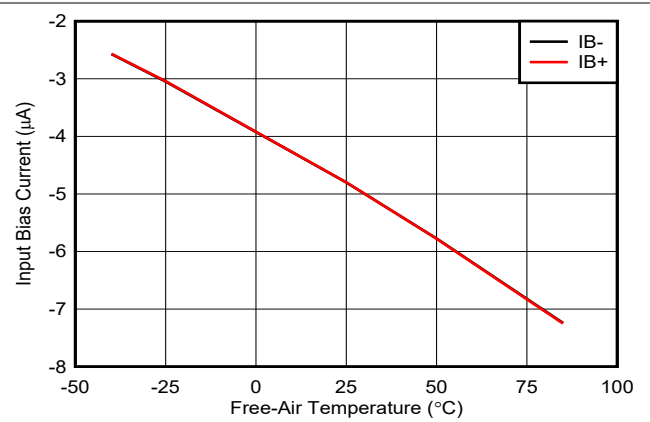
图 **6-26. Input Bias Current vs Free-Air Temperature**
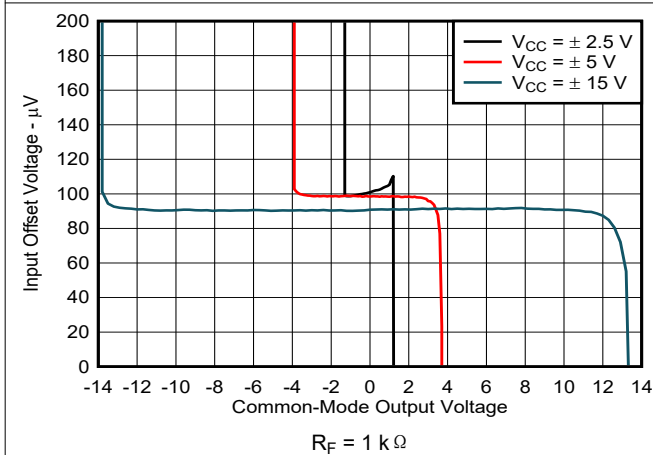
图 **6-27. Input Offset Voltage vs Common-Mode Output Voltage**
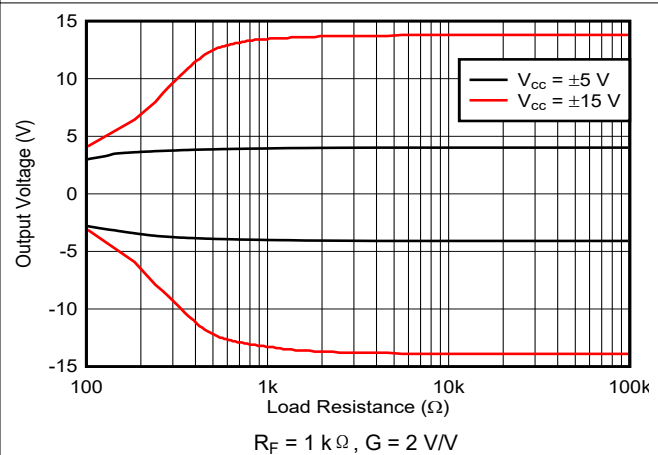
图 **6-28. Output Voltage vs Differential Load Resistance**

Product Folder Links: *THS2630*

English Data Sheet: *SLOSE96*

7 Detailed Description

7.1 Overview

The THS2630 is a fully differential amplifier (FDA). Differential signal processing offers a number of performance advantages in high-speed analog signal processing systems, including immunity to external common-mode noise, suppression of even-order nonlinearities, and increased dynamic range. FDAs not only serve as the primary means of providing gain to a differential signal chain, but also provide a monolithic solution for converting single-ended signals into differential signals allowing for easy, high-performance processing. For more information on the basic theory of operation for FDAs, see the *Fully Differential Amplifiers* application note.

7.2 Functional Block Diagram
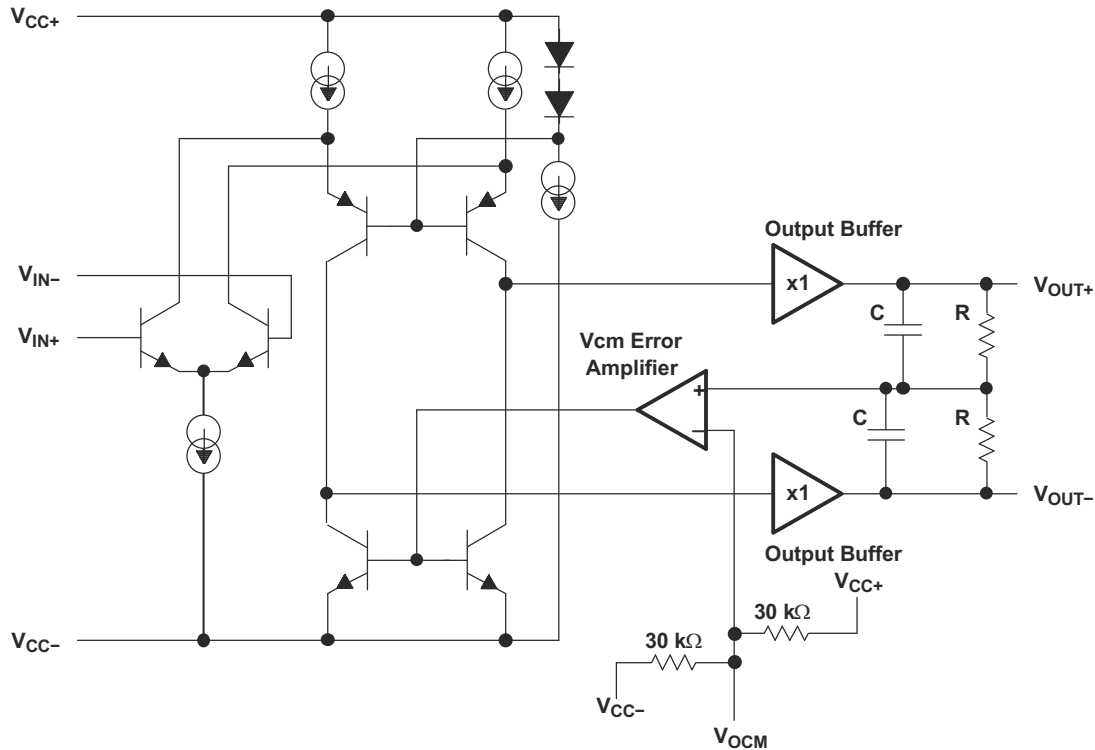
7.3 Feature Description

图 7-1 and 图 7-2 shows the differences between the operation of the THS2630 in two different modes. FDAs can work with either differential or single-ended inputs.
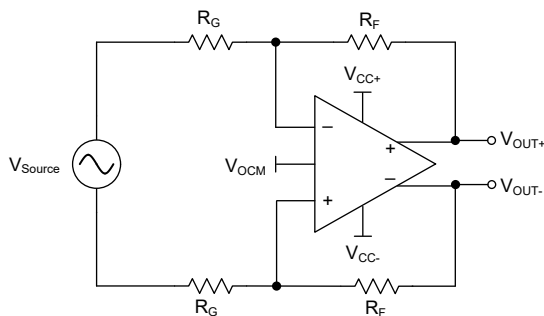
图 7-1. Amplifying Differential Input Signals
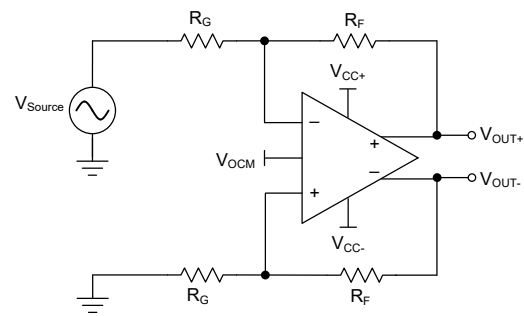
图 7-2. Amplifying Single-ended Input Signals

7.4 Device Functional Modes

7.4.1 Power-Down Mode

Power-down mode is used when power saving is required. The THS2630S power-down ($\overline{\text{PD}}$) pin is an active low input. If left unconnected, an internal 250-kΩ resistor to V_{CC+} keeps the device turned on. The threshold voltage for the power-down function is approximately 1.4 V greater than V_{CC-}. If the $\overline{\text{PD}}$ pin is 1.4 V greater than V_{CC-}, the device is active. If the $\overline{\text{PD}}$ pin is less than 1.4 V greater than V_{CC-}, the device is off. Pull the pin to V_{CC-} to turn the device off. 图 7-3 shows the simplified version of the power-down circuit. While in the power-down state, the amplifier goes into a high-impedance state. The amplifier output impedance is typically greater than 1 MΩ in the power-down state.
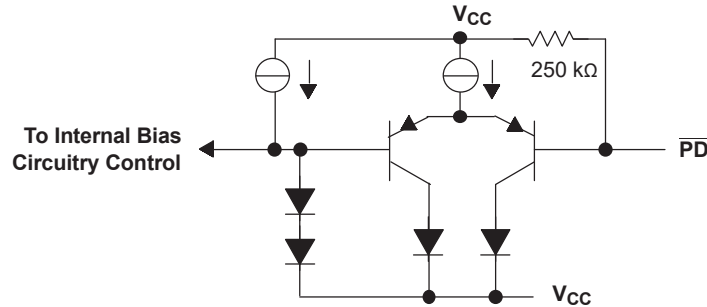
图 7-3. Simplified Power-Down Circuit

Similar to an op amp in an inverting configuration, the output impedance of an FDA is determined by the feedback network configuration. In addition, the THS2630S has an internal 10-kΩ resistor at each output that is tied to the V_{CM} error amplifier (see 节 7.2). The differential output impedance is equal to [(2 × R_F + 2 × R_G) || 20 kΩ]. 图 7-4 shows the closed-loop output impedance of the THS2630S when in power-down.
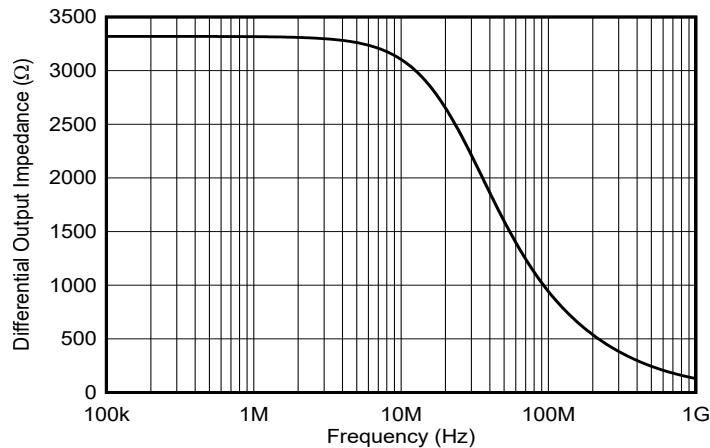
V_{CC} = ±5 V, gain = 1 V/V, R_F = 1 kΩ, $\overline{\text{PD}}$ = V_{CC-}

图 7-4. Output Impedance (in Power-Down) vs Frequency

Product Folder Links: *THS2630*

8 Application and Implementation

备注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

8.1.1 Output Common-Mode Voltage

The output common-mode voltage pin sets the dc output voltage of the THS2630. A voltage applied to the VOCM pin from a low-impedance source can be used to directly set the output common-mode voltage. If left floating, then the VOCM pin defaults to the mid-rail voltage, defined as:

$$\frac{(V_{CC+}) + (V_{CC-})}{2} \tag{1}$$

To minimize common-mode noise, connect a 0.1-µF bypass capacitor to the VOCM pin. Output common-mode voltage causes additional current to flow in the feedback resistor network. This current is supplied by the output stage of the amplifier; therefore, additional power dissipation is created. For commonly-used feedback resistance values, this current is easily supplied by the amplifier. The additional internal power dissipation created by this current can be significant in some applications and can dictate the use of the HVSSOP package to effectively control self-heating.

8.1.1.1 Resistor Matching

Resistor matching is important in FDAs to maintain good output balance. An ideal differential output signal implies the two outputs of the FDA should be exactly equal in amplitude and shifted 180° in phase. Any imbalance in amplitude or phase between the two output signals results in an undesirable common-mode signal at the output. The output balance error is a measure of how well the outputs are balanced and is defined as the ratio of the output common-mode voltage to the output differential signal.

$$Output\ Balance\ Error = \frac{\left(\frac{V_{OUT+} - V_{OUT-}}{2}\right)}{V_{OUT+} - V_{OUT-}} \tag{2}$$

At low frequencies, resistor mismatch is the primary contributor to output balance errors. Additionally CMRR, PSRR, and HD2 performance diminish if resistor mismatch occurs. Therefore, to optimize performance, use 1% tolerance resistors or better. 表 8-1 provides the recommended resistor values to use for a particular gain.

表 8-1. Recommended Resistor Values

GAIN (V/V)	R_G (Ω)	R_F (Ω)
1	390	390
2	374	750
5	402	2010
10	402	4020

8.1.2 Driving a Capacitive Load

Driving capacitive loads with high-performance amplifiers is not a problem as long as certain precautions are taken. The THS2630 has been internally compensated to maximize bandwidth and slew rate performance. When the amplifier is compensated in this manner, capacitive loading directly on the output decreases the device phase margin leading to high-frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10 pF, place a resistor in series with the output of the amplifier, as shown in 图 8-1. A minimum value of 20 Ω works well for most applications. For example, in 50-Ω transmission systems, setting the series resistor value to 50 Ω both isolates any capacitance loading and provides the proper line impedance matching at the source end.
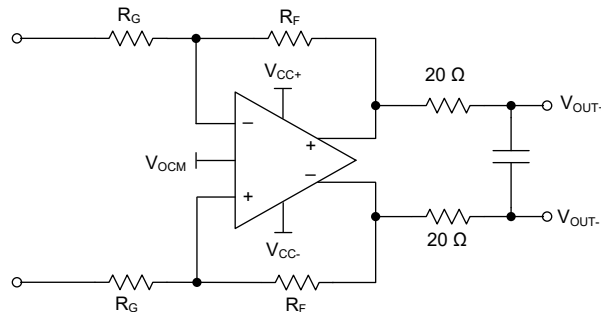
图 8-1. Driving a Capacitive Load

8.1.3 Data Converters

Driving data converters are one of the most popular applications for fully-differential amplifiers. 图 8-2 shows a typical configuration of an FDA attached to a differential analog-to-digital converter (ADC).
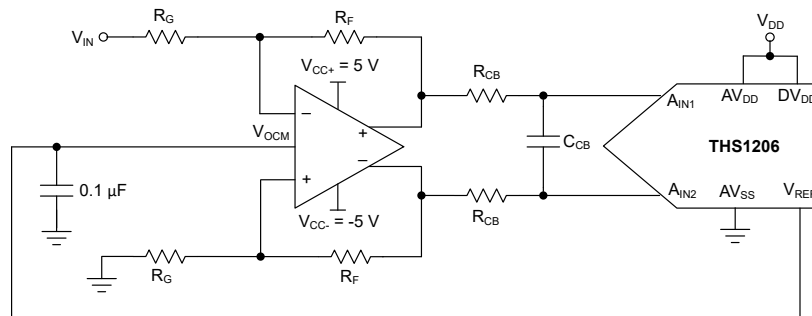
图 8-2. Fully-Differential Amplifier Attached to a Differential ADC

FDAs can operate with a single supply. V_{OCM} defaults to the mid-rail voltage, $V_{CC}/2$. The differential output can be fed into a data converter. This method eliminates the use of a transformer in the circuit. If the ADC has a reference voltage output (V_{ref}), then connect V_{ref} directly to the V_{OCM} of the amplifier using a bypass capacitor to reduce broadband common-mode noise.

Product Folder Links: *THS2630*

English Data Sheet: *SLOSE96*
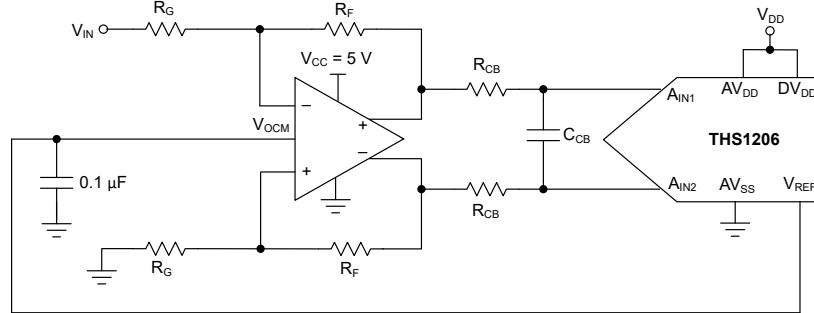
图 8-3. Fully-Differential Amplifier Using a Single Supply

8.1.4 Single-Supply Applications

For proper operation, the input common-mode voltage to the input terminal of the amplifier must not exceed the common-mode input voltage range. However, some single-supply applications can require the input voltage to exceed the common-mode input voltage range. In such cases, to bring the common-mode input voltage within the specifications of the amplifier, the circuit configuration of 图 8-4 is suggested.
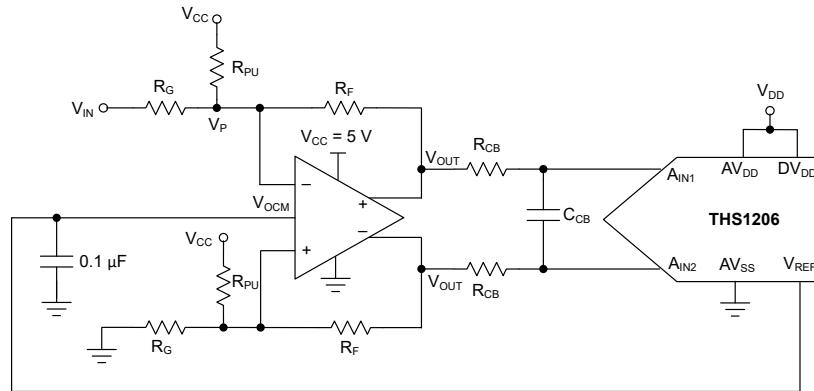
图 8-4. Circuit With Improved Common-Mode Input Voltage

方程式 3 is used to calculate R_{PU}:

$$R_{PU} = \frac{V_P - V_{CC}}{(V_{IN} - V_P)\frac{1}{R_G} + (V_{OUT} - V_P)\frac{1}{R_F}}$$

(3)

8.2 Typical Application

For signal conditioning in ADC applications, it is important to limit the input frequency to the ADC. Low-pass filters can prevent the aliasing of the high-frequency noise with the frequency of operation. 图 8-5 shows a method by which the noise may be filtered in the THS2630.

图 8-5 shows a typical application design example for the THS2630 device in active low-pass filter topology driving and ADC.

Submit Document Feedback 17

Product Folder Links: *THS2630*

English Data Sheet: *SLOSE96*
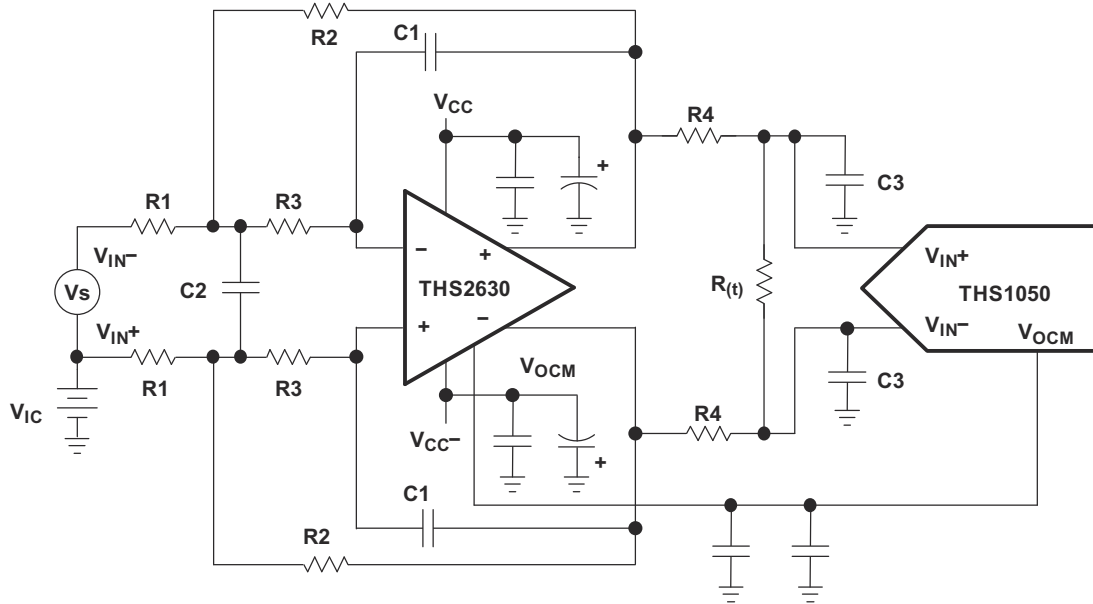
图 **8-5. Antialias Filtering**

8.2.1 Design Requirements

表 8-2 provides example design parameters and values for the typical application design example in 图 8-5.

表 8-2. Design Parameters

DESIGN PARAMETERS	VALUE
Supply voltage	±2.5 V to ±17.5 V
Amplifier topology	Voltage feedback
Output control	DC-coupled with output common-mode control capability
Filter requirement	500-kHz, multiple-feedback low-pass filter

8.2.2 Detailed Design Procedure

8.2.2.1 Active Antialias Filtering

图 8-5 shows a multiple-feedback (MFB) lowpass filter. The transfer function for this filter circuit is:

$$H_d(f) = \left[\frac{K}{-\left[\frac{f}{FSF \times fc}\right]^2 + \frac{1}{Q}\frac{jf}{FSF \times fc} + 1} \right] \times \left[\frac{\frac{Rt}{2R4 + Rt}}{1 + \frac{j2\pi f R4 Rt C3}{2R4 + Rt}} \right] \; Where \; K = \frac{R2}{R1} \tag{4}$$

$$FSF \times fc = \frac{1}{2\pi\sqrt{2 \times R2R3C1C2}} \; and \; Q = \frac{\sqrt{2 \times R2R3C1C2}}{R3C1 + R2C1 + KR3C1} \tag{5}$$

K sets the pass band gain, fc is the cutoff frequency for the filter, FSF is a frequency scaling factor, and Q is the quality factor.

$$FSF = \sqrt{Re^2 + |Im|^2} \; and \; Q = \frac{\sqrt{Re^2 + |Im|^2}}{2Re} \tag{6}$$

where Re is the real part, and Im is the imaginary part of the complex pole pair. Setting R2 = R, R3 = mR, C1 = C, and C2 = nC results in:

$$FSF \times fc = \frac{1}{2\pi Rc\sqrt{2 \times mn}} \; and \; Q = \frac{\sqrt{2 \times mn}}{1 + m(1 + K)} \tag{7}$$

Product Folder Links: *THS2630*

English Data Sheet: SLOSE96

Start by determining the ratios, m and n, required for the gain and Q of the filter type being designed, then select C and calculate R for the desired fc.

8.2.3 Application Curve
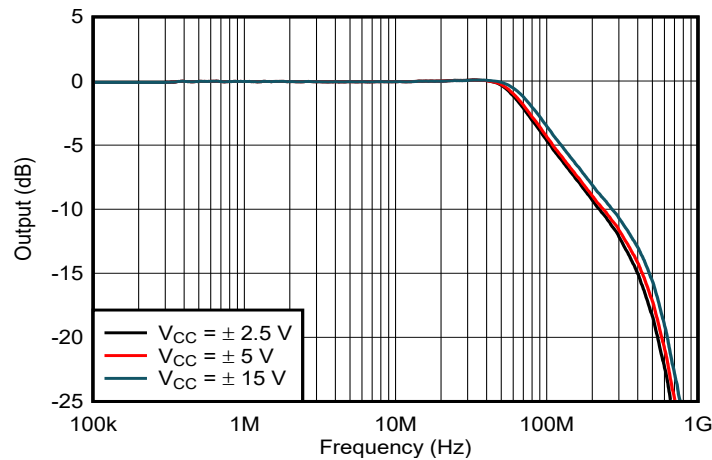
图 8-6. Large-Signal Frequency Response

8.3 Power Supply Recommendations

The THS2630 devices are designed to operate on power supplies ranging from ±2.5 V to ±15 V (single-ended supplies of 5 V to 30 V). Use a power-supply accuracy of 5% or better. When operated on a board with high-speed digital signals, make sure to provide isolation between digital signal noise and the analog input pins. The THS2630 are connected to power supplies through pin 3 (V_{CC+}) and pin 6 (V_{CC-}). Decouple each supply pin to GND as close to the device as possible with a low-inductance, surface-mount ceramic capacitor of approximately 10 nF. When vias are used to connect the bypass capacitors to a ground plane, configure the vias for minimal parasitic inductance. One method of reducing via inductance is to use multiple vias. For broadband systems, two capacitors per supply pin are advised.

To avoid undesirable signal transients, do not power on the THS2630 with large inputs signals present. Careful planning of system power on sequencing is especially important to avoid damage to ADC inputs when an ADC is used in the application.

8.4 Layout

8.4.1 Layout Guidelines

To achieve the levels of high-frequency performance of the THS2630, follow proper printed-circuit board (PCB) high-frequency design techniques. Following is a general set of guidelines. In addition, a SLOU554 is available to use as a guide for layout or for evaluating device performance.

- Ground planes—Use a ground plane on the board to provide all components with a low inductive ground connection. However, in the areas of the amplifier inputs and output, the ground plane can be removed to minimize the stray capacitance.
- Proper power-supply decoupling—use a 6.8-μF tantalum capacitor in parallel with a 0.1-μF ceramic capacitor on each supply pin. Sharing the tantalum among several amplifiers is possible depending on the application; however, always use a 0.1-μF ceramic capacitor on the supply pin of every amplifier. In addition, place the 0.1-μF capacitor as close as possible to the supply pin. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. Strive for distances of less than 0.1 inches between the device power pin and the ceramic capacitors.
- Short trace runs or compact part placements—to optimize high-frequency performance, minimize stray series inductance. The best method is to make the circuit layout as compact as possible, thereby minimizing the length of all trace runs. Pay particular attention to the inputs of the amplifier; keep the length as short as possible. This short length helps minimize stray capacitance at the input of the amplifier.

8.4.1.1 PowerPAD™ Integrated Circuit Package Design Considerations

The THS2630 is available in a thermally-enhanced DGN package, which is a member of the PowerPAD™ integrated circuit package family. This package is constructed using a downset leadframe upon which the die is mounted (see 图 8-7 **a** and 图 8-7 **b**). This arrangement results in the lead frame being exposed as a thermal pad on the underside of the package (see 图 8-7 **c**). Because this thermal pad has direct thermal contact with the die, excellent thermal performance can be achieved by providing a good thermal path away from the thermal pad.

The PowerPAD package allows for both assembly and thermal management in one manufacturing operation. During the surface-mount solder operation (when the leads are being soldered), the thermal pad can also be soldered to a copper area underneath the package. Through the use of thermal paths within this copper area, heat can be conducted away from the package into either a ground plane or other heat dissipating device.

The PowerPAD package represents a breakthrough in combining the small area and ease of assembly of the surface mount with the previously awkward mechanical methods of using a heat sink.

More complete details of the PowerPAD installation process and thermal management techniques can be found in *PowerPAD Thermally-Enhanced Package* application report. This document can be found on the TI website at www.ti.com by searching for the keyword PowerPAD. The document can also be ordered through your local TI sales office; refer to SLMA002 when ordering.

Side View (a)

End View (b)

Bottom View (c)
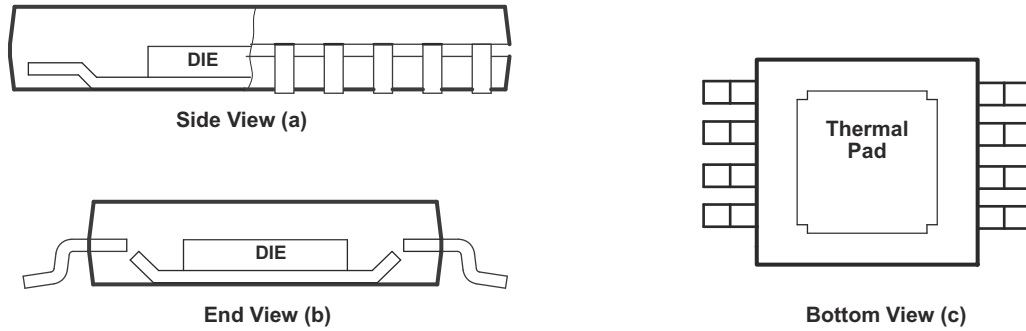
Note: The thermal pad (PowerPAD) is electrically isolated from all other pins and can be connected to any potential from V_{CC-} to V_{CC+}. Typically, the thermal pad is connected to the ground plane because this plane tends to physically be the largest and is able to dissipate the most amount of heat.

图 8-7. Views of Thermally-Enhanced DGN Package

8.4.2 Layout Example
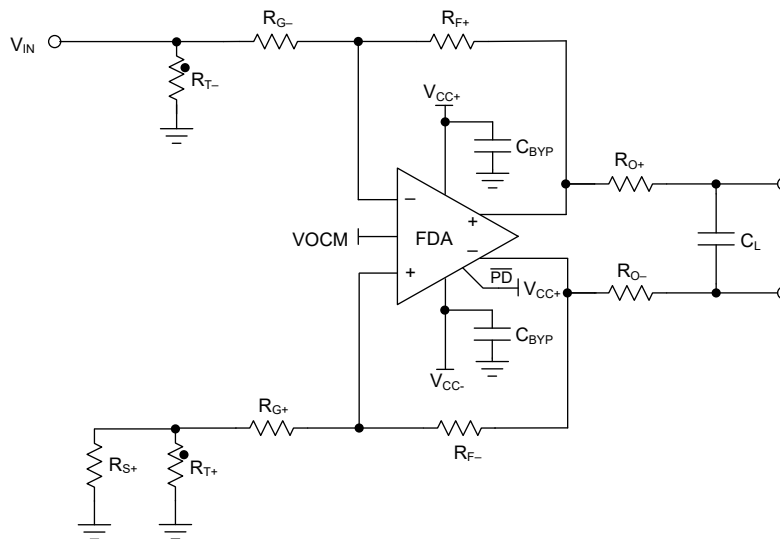
图 8-8. Representative Schematic for Layout
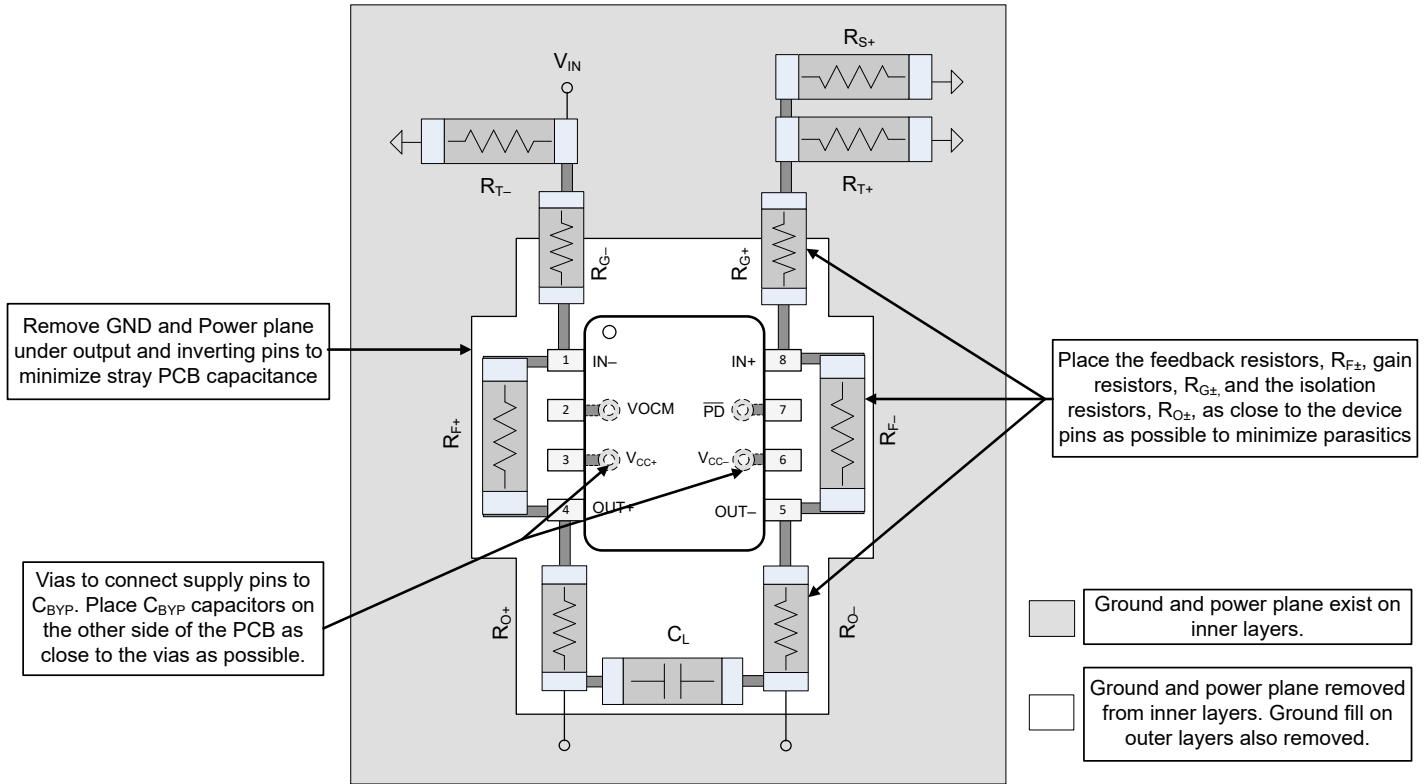
图 **8-9. Layout Recommendations**

Product Folder Links: *THS2630*

English Data Sheet: *SLOSE96*

9 Device and Documentation Support

9.1 Documentation Support

9.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, *Design Guide for 2.3 nV/ √Hz, Differential, Time Gain Control (TGC) DAC Reference Design for Ultrasound* design guide
- Texas Instruments, *EVM User's Guide for High-Speed Fully-Differential Amplifier* user's guide
- Texas Instruments, *Fully Differential Amplifiers* application note
- Texas Instruments, *Maximizing Signal Chain Distortion Performance Using High Speed Amplifiers* application note
- Texas Instruments, *PowerPAD Thermally-Enhanced Package* technical brief
- Texas Instruments, *TI Precision Labs - Fully Differential Amplifiers* video series

9.2 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击*订阅更新* 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

9.3 支持资源

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链接的内容由各个贡献者"按原样"提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅TI 的《使用条款》。

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ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

9.6 术语表

TI 术语表   本术语表列出并解释了术语、首字母缩略词和定义。

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
THS2630DGKR	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2UP5	Samples
THS2630DGNR	ACTIVE	HVSSOP	DGN	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	2UQJ	Samples
THS2630DR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	T2630	Samples
THS2630SDGKR	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2UO5	Samples
THS2630SDGNR	ACTIVE	HVSSOP	DGN	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	2URJ	Samples
THS2630SDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	T2630S	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
THS2630DGKR	VSSOP	DGK	8	2500	330.0	12.4	5.25	3.35	1.25	8.0	12.0	Q1
THS2630DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
THS2630DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
THS2630SDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.25	3.35	1.25	8.0	12.0	Q1
THS2630SDGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
THS2630SDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
THS2630DGKR	VSSOP	DGK	8	2500	366.0	364.0	50.0
THS2630DGNR	HVSSOP	DGN	8	2500	356.0	356.0	35.0
THS2630DR	SOIC	D	8	2500	356.0	356.0	35.0
THS2630SDGKR	VSSOP	DGK	8	2500	366.0	364.0	50.0
THS2630SDGNR	HVSSOP	DGN	8	2500	356.0	356.0	35.0
THS2630SDR	SOIC	D	8	2500	356.0	356.0	35.0

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.
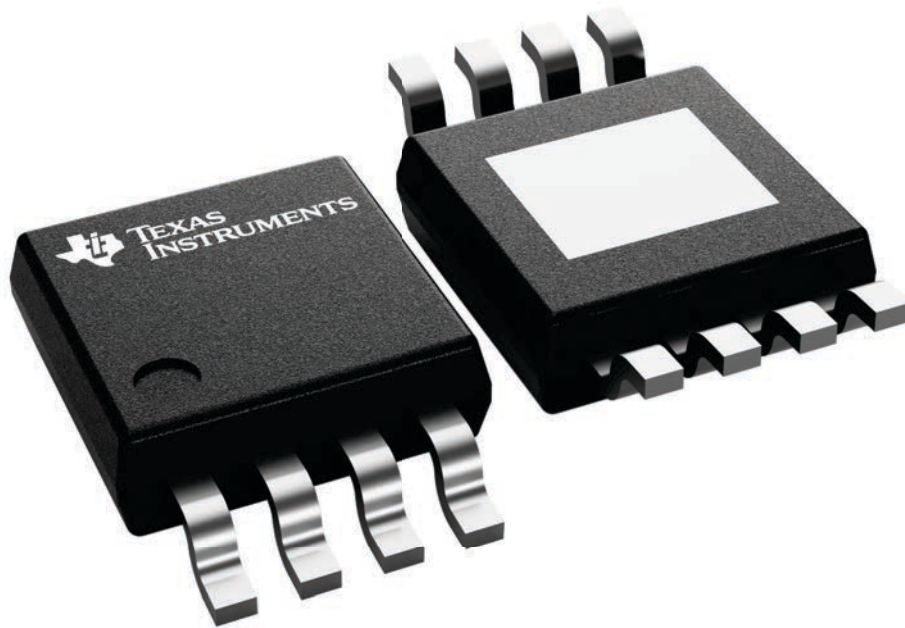
4225482/B
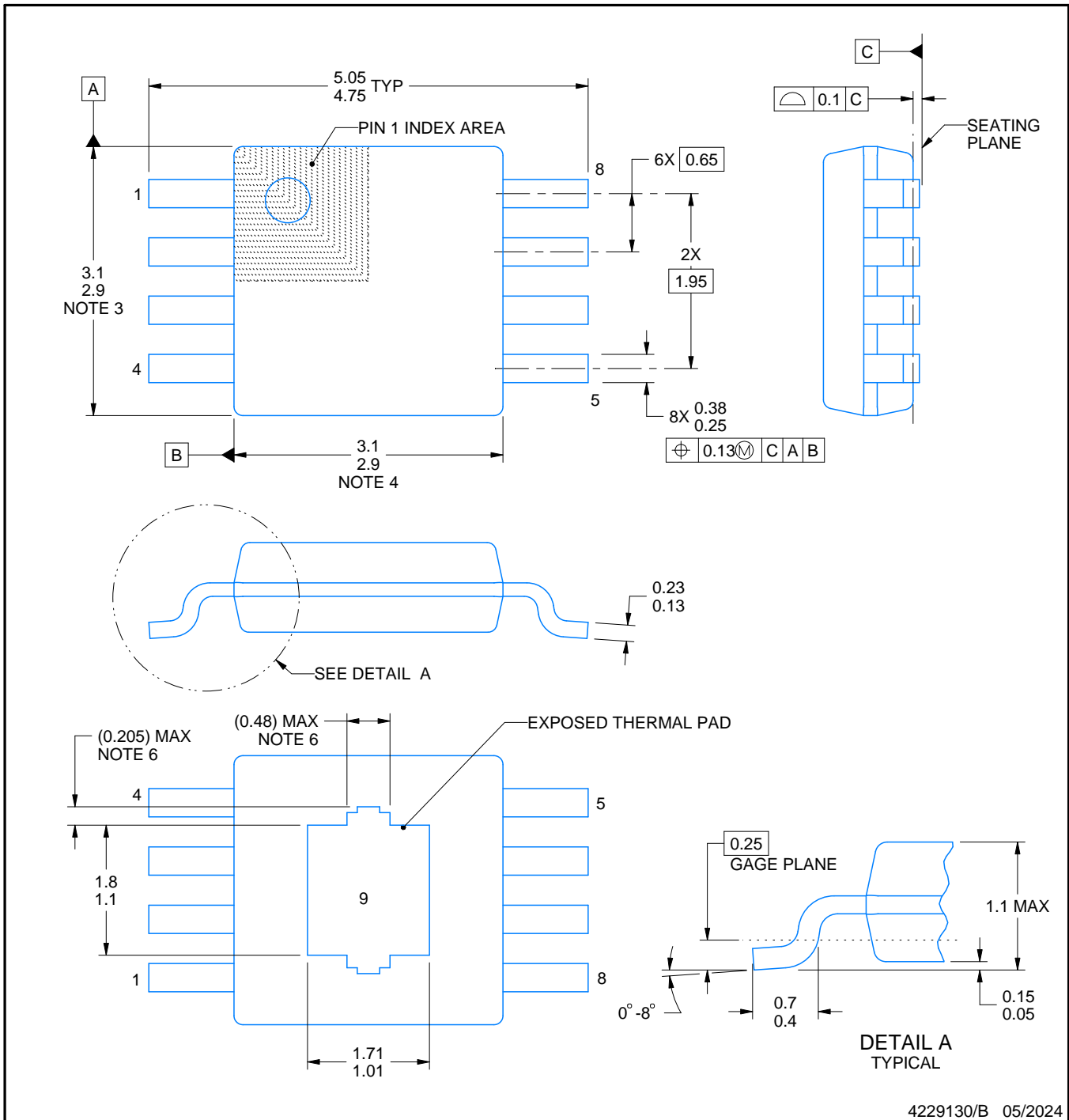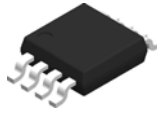
4229130/B   05/2024

PowerPAD is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.
6. Features may differ or may not be present.

DGN0008H

METAL COVERED
BY SOLDER MASK

(2)
NOTE 10

(1.71)

SYMM
₵

SOLDER MASK
DEFINED PAD

(R0.05) TYP

8X (1.4)

8X (0.45)   1

8

9

SYMM
₵

(3)
NOTE 10

(1.8)

6X (0.65)

(1.22)

4

5

(⌀ 0.2) TYP
VIA

SEE DETAILS

(0.55)

(4.4)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X

SOLDER MASK
OPENING

METAL

EXPOSED METAL

0.05 MAX
ALL AROUND

NON-SOLDER MASK
DEFINED
(PREFERRED)

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

0.05 MIN
ALL AROUND

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4229130/B   05/2024

NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.
8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
9. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
10. Size of metal pad may vary due to creepage requirement.

(1.71)
BASED ON
0.125 THICK
STENCIL

SYMM

8X (1.4)

8X (0.45) 1

(R0.05) TYP

8

SYMM

(1.8)
BASED ON
0.125 THICK
STENCIL

6X (0.65)

4

5

METAL COVERED
BY SOLDER MASK

SEE TABLE FOR
DIFFERENT OPENINGS
FOR OTHER STENCIL
THICKNESSES

(4.4)

SOLDER PASTE EXAMPLE
EXPOSED PAD 9:
100% PRINTED SOLDER COVERAGE BY AREA
SCALE: 15X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	1.91 X 2.01
0.125	1.71 X 1.80 (SHOWN)
0.15	1.56 X 1.64
0.175	1.45 X 1.52

4229130/B 05/2024

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

.228-.244   TYP
[5.80-6.19]

PIN 1 ID AREA

A

1

8

6X .050
[1.27]

2X

.150
[3.81]

5

8X .012-.020
[0.31-0.51]

⊕ .010 [0.25] Ⓜ C A B

4

.189-.197
[4.81-5.00]
NOTE 3

B

.150-.157
[3.81-3.98]
NOTE 4

C

SEATING PLANE

◯ .004 [0.1] C

4X (0°-15°)

.069 MAX
[1.75]

SEE DETAIL A

4X (0°-15°)

.005-.010   TYP
[0.13-0.25]

.010
[0.25]

0°- 8°

.016-.050
[0.41-1.27]

(.041)
[1.04]

.004-.010
[0.11-0.25]

DETAIL A
TYPICAL

4214825/C   02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches.
   Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
   exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

8X (.061)
[1.55]

SYMM
₵

SEE
DETAILS

1

8

8X (.024)
[0.6]

SYMM
₵

(R.002) TYP
[0.05]

6X (.050)
[1.27]

4

5

(.213)
[5.4]

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X

METAL

SOLDER MASK
OPENING

SOLDER MASK
OPENING

METAL UNDER
SOLDER MASK

EXPOSED
METAL

EXPOSED
METAL

.0028 MAX
[0.07]
ALL AROUND

.0028 MIN
[0.07]
ALL AROUND

NON SOLDER MASK
DEFINED

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4214825/C   02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

8X (.061)
[1.55]

1

8X (.024)
[0.6]

SYMM

SYMM

8

(R.002) TYP
[0.05]

4
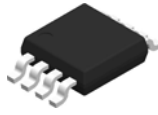
5

6X (.050)
[1.27]

(.213)
[5.4]

SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate
   design recommendations.
9. Board assembly site may have different recommendations for stencil design.

5.05 / 4.75 TYP

A

PIN 1 INDEX AREA

1

8

6X 0.65

3.1 / 2.9
NOTE 3

2X
1.95

4

5

8X 0.38 / 0.25

B

3.1 / 2.9
NOTE 4

⊕ 0.13 Ⓜ C A B

C

⌒ 0.1 C

SEATING PLANE

0.23 / 0.13

SEE DETAIL A

0.25
GAGE PLANE

1.1 MAX

0° -8°

0.7 / 0.4

0.15 / 0.05

DETAIL A
TYPICAL

4214862/A   04/2023

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4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

SYMM

8X (1.4)

(R0.05) TYP

8X (0.45)   1

8

SYMM

6X (0.65)

4

5

SEE DETAILS

(4.4)

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X

SOLDER MASK OPENING

METAL

METAL UNDER SOLDER MASK

SOLDER MASK OPENING

EXPOSED METAL

EXPOSED METAL

0.05 MAX
ALL AROUND

0.05 MIN
ALL AROUND

NON-SOLDER MASK
DEFINED
(PREFERRED)

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4214862/A   04/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
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9. Size of metal pad may vary due to creepage requirement.

SYMM

8X (1.4)

8X (0.45) 1

(R0.05) TYP

8

SYMM

6X (0.65)

4

5

(4.4)

SOLDER PASTE EXAMPLE
SCALE: 15X

4214862/A   04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.